PZT2222AT1

NPN Silicon Planar Epitaxial Transistor

This NPN Silicon Epitaxial transistor is designed for use in linear and switching applications. The device is housed in the SOT-223 package which is designed for medium power surface mount applications.

Features

- PNP Complement is PZT2907AT1
- The SOT-223 Package Can be Soldered Using Wave or Reflow
- SOT-223 Package Ensures Level Mounting, Resulting in Improved Thermal Conduction, and Allows Visual Inspection of Soldered Joints
- The Formed Leads Absorb Thermal Stress During Soldering, Eliminating the Possibility of Damage to the Die
- Available in 12 mm Tape and Reel
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS

Rating	Symbol	Value	Unit		
Collector-Emitter Voltage	V _{CEO}	40	Vdc		
Collector-Base Voltage	V _{CBO}	75	Vdc		
Emitter-Base Voltage (Open Collector)	V _{EBO}	6.0	Vdc		
Collector Current	Ι _C	600	mAdc		
Total Power Dissipation up to T _A = 25°C (Note 1)	P _D	1.5	W		
Storage Temperature Range	T _{stg}	- 65 to +150	°C		
Junction Temperature	TJ	150	°C		

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Device mounted on an epoxy printed circuit board 1.575 inches x 1.575 inches x 0.059 inches; mounting pad for the collector lead min. 0.93 inches².

THERMAL CHARACTERISTICS

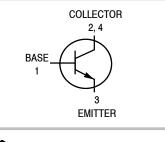
Rating	Symbol	Value	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	83.3	°C/W
Lead Temperature for Soldering, 0.0625" from case Time in Solder Bath	ΤL	260 10	°C Sec



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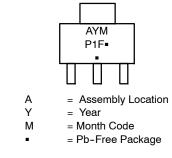
http://onsemi.com

SOT-223 PACKAGE NPN SILICON TRANSISTOR SURFACE MOUNT





MARKING DIAGRAM



(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping [†]
PZT2222AT1G	SOT-223 (Pb-Free)	1000 Tape & Reel
PZT2222AT3G	SOT-223 (Pb-Free)	4000 Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please

refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

	Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERIST					
Collector-Emitter Bre	akdown Voltage (I _C = 10 mAdc, I _B = 0)	V _{(BR)CEO}	40	-	Vdc
Collector-Base Break	kdown Voltage (I _C = 10 μAdc, I _E = 0)	V _{(BR)CBO}	75	-	Vdc
Emitter-Base Breakd	own Voltage ($I_E = 10 \ \mu Adc, I_C = 0$)	V _{(BR)EBO}	6.0	-	Vdc
Base-Emitter Cutoff	Current (V _{CE} = 60 Vdc, V _{BE} = - 3.0 Vdc)	I _{BEX}	-	20	nAdc
Collector-Emitter Cut	off Current (V _{CE} = 60 Vdc, V _{BE} = - 3.0 Vdc)	I _{CEX}	-	10	nAdc
Emitter-Base Cutoff	Current (V _{EB} = 3.0 Vdc, I _C = 0)	I _{EBO}	-	100	nAdc
Collector-Base Cutof $(V_{CB} = 60 \text{ Vdc}, I_E = (V_{CB} = 60 \text{ Vdc}, I_E = 0 \text{ Vdc}, I_E = 0 \text{ Vdc}, I_E = 0 \text{ Vdc}$	= 0)	Ісво	-	10 10	nAdc μAdc
ON CHARACTERISTI	cs				
$\begin{array}{l} \text{DC Current Gain} \\ (I_{C}=0.1 \text{ mAdc}, V_{C} \\ (I_{C}=1.0 \text{ mAdc}, V_{CE} \\ (I_{C}=10 \text{ mAdc}, V_{CE} \\ (I_{C}=10 \text{ mAdc}, V_{CE} \\ (I_{C}=150 \text{ mAdc}, V_{CE} \\ (I_{C}=150 \text{ mAdc}, V_{CE} \\ (I_{C}=500 \text{ mAdc}, V_{CE} \\ (I_{C}=500 \text{ mAdc}, V_{CE} \\ (I_{C}=150 $	_E = 10 Vdc) = 10 Vdc) = 10 Vdc, T _A = - 55°C) _{CE} = 10 Vdc) _{CE} = 1.0 Vdc)	hFE	35 50 70 35 100 50 40	- - - 300 - -	-
Collector-Emitter Sat ($I_C = 150 \text{ mAdc}, I_B$ ($I_C = 500 \text{ mAdc}, I_B$	= 15 mAdc)	V _{CE(sat)}		0.3 1.0	Vdc
Base-Emitter Saturat (I _C = 150 mAdc, I _B (I _C = 500 mAdc, I _B	V _{BE(sat)}	0.6 -	1.2 2.0	Vdc	
Input Impedance (V_{CE} = 10 Vdc, I_C = (V_{CE} = 10 Vdc, I_C =	h _{ie}	2.0 0.25	8.0 1.25	kΩ	
	tio = 1.0 mAdc, f = 1.0 kHz) = 10 mAdc, f = 1.0 kHz)	h _{re}	-	8.0x10 ⁻⁴ 4.0x10 ⁻⁴	-
Small-Signal Current (V _{CE} = 10 Vdc, I _C = (V _{CE} = 10 Vdc, I _C =	h _{fe}	50 75	300 375	-	
Output Admittance (V _{CE} = 10 Vdc, I _C = (V _{CE} = 10 Vdc, I _C =	h _{oe}	5.0 25	35 200	μmhos	
Noise Figure ($V_{CE} = -$	10 Vdc, I _C = 100 μAdc, f = 1.0 kHz)	F	-	4.0	dB
DYNAMIC CHARACT	ERISTICS				
Current-Gain - Band (I _C = 20 mAdc, V _{CE}	width Product ₌ = 20 Vdc, f = 100 MHz)	fT	300	-	MHz
Output Capacitance (C _c	-	8.0	pF	
Input Capacitance (V	C _e	-	25	pF	
	$\Gamma_A = 25^{\circ}C$				
	$ \begin{array}{ c c c c c } \hline (V_{CC} = 30 \ Vdc, \ I_C = 150 \ mAdc, \\ \hline I_{B(on)} = 15 \ mAdc, \ V_{EB(off)} = 0.5 \ Vdc) \\ \hline Figure \ 1 & & & \\ \hline t_r & - & 25 \end{array} $		ns		
			25		
Storage Time $(V_{CC} = 30 \text{ Vdc}, I_C = 150 \text{ mAdc},$ $I_{B(on)} = I_{B(off)} = 15 \text{ mAdc}$		t _s	-	225	ns
Fall Time F	t _f	-	60	1	

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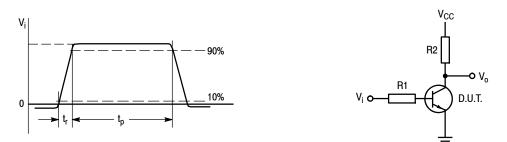


Figure 1. Input Waveform and Test Circuit for Determining Delay Time and Rise Time

V _i = - 0.5 V to +9.9 V,	$V_{CC}=\texttt{+30}~V,R1=\texttt{619}~\Omega,$	R2 = 200 Ω.	
PULSE GENERATOR:		OSCILLOSCOPE:	
PULSE DURATION	t _n 3 200 ns	INPUT IMPEDANCE	Z _i > 100 kΩ
RISE TIME	t <mark>r</mark> 3 2 ns	INPUT CAPACITANCE	C _i < 12 pF
DUTY FACTOR	$\delta = 0.02$	RISE TIME	t _r < 5 ns

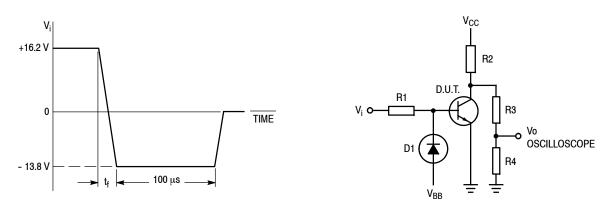
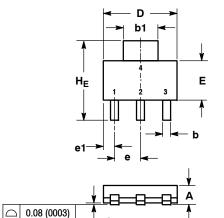


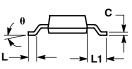
Figure 2. Input Waveform and Test Circuit for Determining Storage Time and Fall Time

PACKAGE DIMENSIONS

SOT-223 (TO-261) CASE 318E-04

ISSUE N





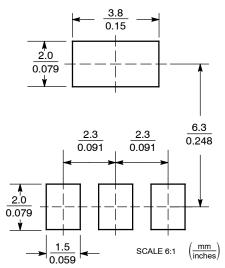
NOTES: 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M,

199	14.					
2. CONTROLLING DIMENSION: INCH.						
	MILLIMETERS		INCHES			
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	1.50	1.63	1.75	0.060	0.064	0.068
A1	0.02	0.06	0.10	0.001	0.002	0.004
b	0.60	0.75	0.89	0.024	0.030	0.035
b1	2.90	3.06	3.20	0.115	0.121	0.126
с	0.24	0.29	0.35	0.009	0.012	0.014
D	6.30	6.50	6.70	0.249	0.256	0.263
Е	3.30	3.50	3.70	0.130	0.138	0.145
е	2.20	2.30	2.40	0.087	0.091	0.094
e1	0.85	0.94	1.05	0.033	0.037	0.041
L	0.20			0.008		
L1	1.50	1.75	2.00	0.060	0.069	0.078
HE	6.70	7.00	7.30	0.264	0.276	0.287
θ	0°	-	10°	0°	-	10°

2. COLLECTOR 3. EMITTER 4. COLLECTOR

STYLE 1: PIN 1. BASE

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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